



SURFACE MOUNT ULTRAFAST RECOVERY RECTIFIER

Reverse Voltage - 50 to 1000 V

Forward Current - 1 A

FEATURES

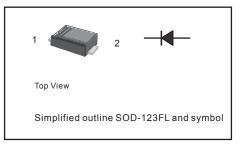
- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- · High efficiency
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: SOD-123FL
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 15mg 0.00053oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

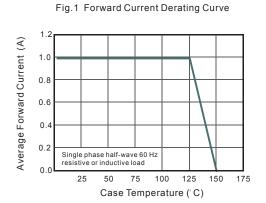
Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	U1A	U1B	U1D	U1G	U1J	U1K	U1M	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	٧
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	٧
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	٧
Maximum Average Forward Rectified Current at T _c = 125 °C	I _{F(AV)}	1							А
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I _{FSM}	30							А
Maximum Instantaneous Forward Voltage at 1 A	V _F	1.0 1.3 1.65					٧		
Maximum DC Reverse Current $T_a = 25$ °C at Rated DC Blocking Voltage $T_a = 125$ °C	I _R	5 100							μА
Maximum Reverse Recovery Time (1)	t _{rr}	50 75						ns	
Typical Thermal Resistance (2)	R _{0JA}	85							°C/W
Operating and Storage Temperature Range	T_{j}, T_{stg}	-55 ~ +150							°C

⁽¹⁾ Measured with $I_F = 0.5 A$, $I_R = 1 A$, $I_{rr} = 0.25 A$.

⁽²⁾ P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.





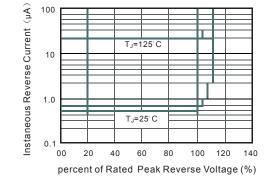
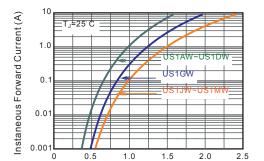
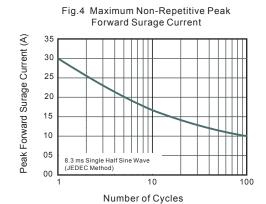


Fig.2 Typical Reverse Characteristics



Instaneous Forward Voltage (V)

Fig.3 Typical Forward Characteristics



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